



DMN1003UCA6

### **Product Summary**

BV <sub>SSS</sub>	Rss(on) typ	I <sub>S Max</sub> Та = +25°С
12V	$2.5m\Omega @ V_{GS} = 3.8V$	23.6A

### Description

This new generation MOSFET has been designed to minimize the onstate resistance ( $R_{SS(ON)}$ ) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

# Applications

- Battery Management
- Load Switch
- Battery Protection

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1	2	3
1. Source 1 2. Gate 1		Top View
3. Source 1		
4. Source 2		
5. Gate 2		
6. Source 2		

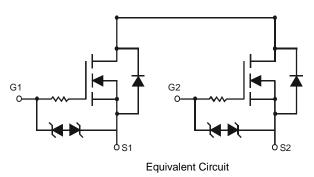
### N-CHANNEL ENHANCEMENT MODE MOSFET

#### Features

- CSP with Footprint 3.54mm × 1.77mm
- Height = 0.21mm for Low Profile
- ESD Protection of Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

## **Mechanical Data**

- Case: X3-DSN3518-6
- Terminal Connections: See Diagram Below
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu. Solderable per MIL-STD-202, Method 208 @4
- Weight: 0.0026 grams (Approximate)



### Ordering Information (Note 4)

Part Number	Case	Packaging
DMN1003UCA6-7	X3-DSN3518-6	3000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**

	M 1	
•	ΥM	

M1 = Product Type Marking Code

YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: G = 2019)

M or  $\overline{M}$  = Month (ex: 9 = September)

#### Date Code Key

Year	2017	2018	20	019	2020	2021		2022	2023	202	24	2025
Code	E	F		G	Н			J	К	L		М
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Source-Source Voltage	Vsss	12	V		
Gate-Source Voltage			Vgss	±8	V
Continuous Source Current (Note 5) V <sub>GS</sub> = 4.5V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ls	23.6 18.9	А
Continuous Source Current (Note 5) VGs = 2.5V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ls	16.8 13.4	А
Pulsed Source Current (Note 6)	lsм	100	А		

# **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 7)	PD	1.05	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 7)	R <sub>0JA</sub>	120.7	°C/W
Power Dissipation (Note 5)	PD	2.67	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 5)	Reja	46.8	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

### Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Source-Source Breakdown Voltage	BVsss	12	_	_	V	$V_{GS} = 0V$ , $I_{S} = 1mA$
Zero Gate Voltage Source Current TJ = +25°C	lsss	_		1	μΑ	$V_{SS} = 10V, V_{GS} = 0V$
Gate-Source Leakage	I <sub>GSS</sub>	_		±10	μA	$V_{GS} = \pm 8V, V_{SS} = 0V$
ON CHARACTERISTICS (Note 8)	-					
Gate Threshold Voltage	V <sub>GS(TH)</sub>	0.5	—	1.3	V	Vss = 6V, Is = 1mA
		1.6	2.3	3.2		$V_{GS} = 4.5V, I_S = 5A$
		1.7	2.4	3.2		V <sub>GS</sub> = 4.0V, I <sub>S</sub> = 5A
Static Source-Source On-Resistance	Rss(ON)	1.8	2.5	3.2	mΩ	V <sub>GS</sub> = 3.8V, I <sub>S</sub> = 5A
		1.9	2.7	4.4		$V_{GS} = 3.1V, I_S = 5A$
		2.1	3.0	6.3		V <sub>GS</sub> = 2.5V, I <sub>S</sub> = 5A
Diode Forward Voltage	Vss	—	0.7	1.2	V	$V_{GS} = 0V$ , $I_S = 3A$
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	Ciss		3315	—		
Output Capacitance	Coss	—	850	—	pF	Vss = 6V, Vgs = 0V, f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	248	—		1 - 1.00012
Total Gate Charge	Qg	_	56.5	_		
Gate-Source Charge	Qgs	_	8.8 —		nC	$V_{SS} = 6V, V_{GS} = 4.5V,$
Gate-Drain Charge	Qgd	_	13.3	_	nc	I <sub>S</sub> = 27A
Gate Charge at Vтн	Qg(TH)	-	6.9			
Turn-On Delay Time	tD(ON)	—	603	—		
Turn-On Rise Time	t <sub>R</sub>	—	1694	—		$V_{SS} = 6V, V_{GS} = 4.5V,$
Turn-Off Delay Time	tD(OFF)	—	4749	—	ns	Is = 3A
Turn-Off Fall Time	tF	—	6208	—		

 Device mounted on FR-4 material with 1-inch<sup>2</sup> (6.45-cm<sup>2</sup>), 2-oz. (0.071-mm thick) Cu.
Repetitive rating, pulse width limited by junction temperature.
Device mounted on FR-4 PCB with minimum recommended pad layout, single sided. Notes:

8. Short duration pulse test used to minimize self-heating effect.

9. Guaranteed by design. Not subject to production testing.



= 1.5V

= 2.0V

 $V_{GS} = 1.2V$ 

<sub>GS</sub> = 3.0V

<sub>cs</sub> = 8.0V

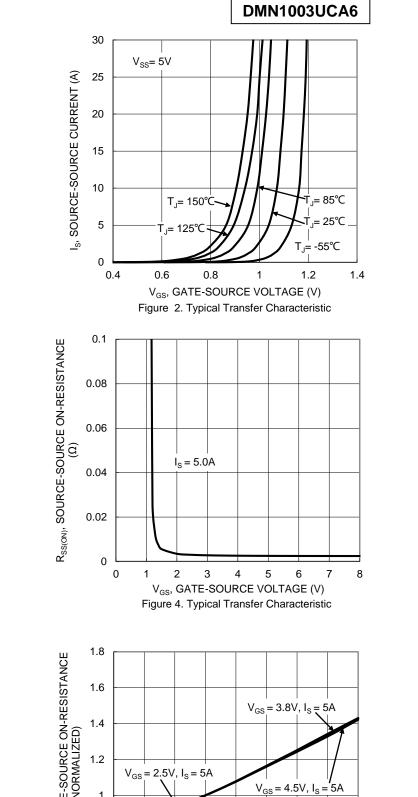
= 4.5V

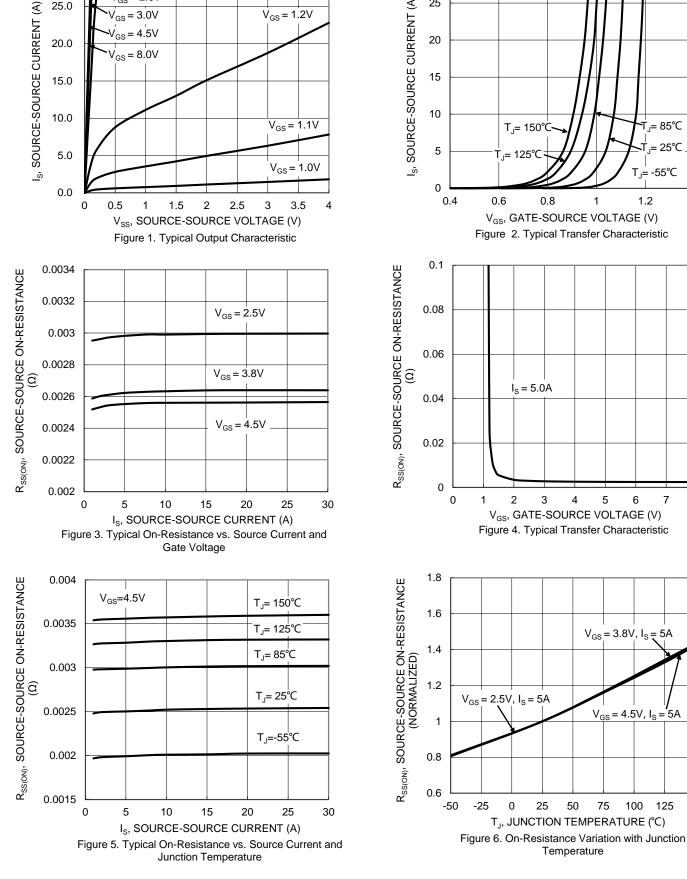
30.0

25.0

20.0

15.0





125

150

DMN1003UCA6 Document number: DS39389 Rev. 6 - 2 -25

0

25

50

Temperature

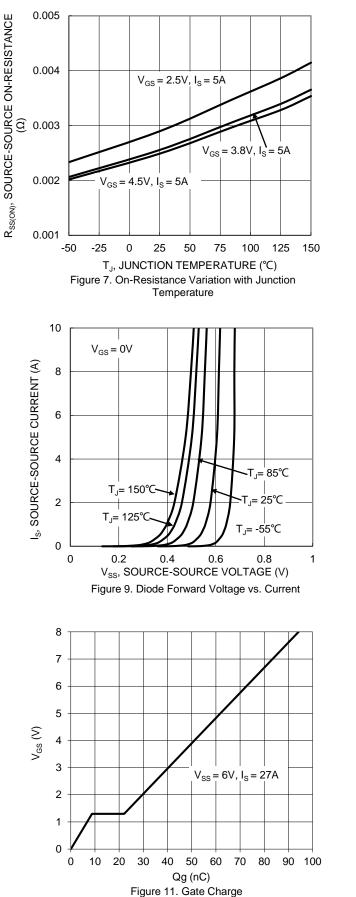
T,, JUNCTION TEMPERATURE (°C)

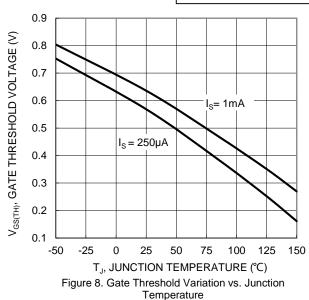
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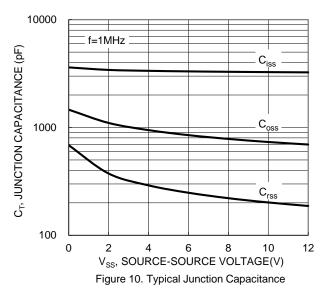
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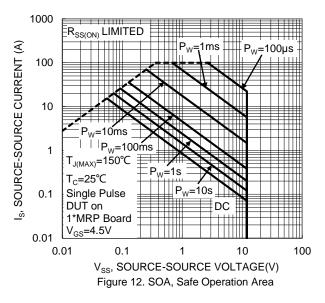


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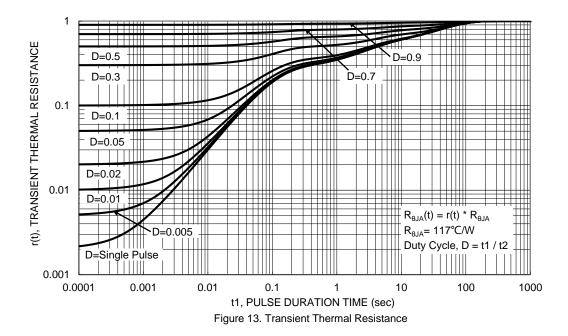










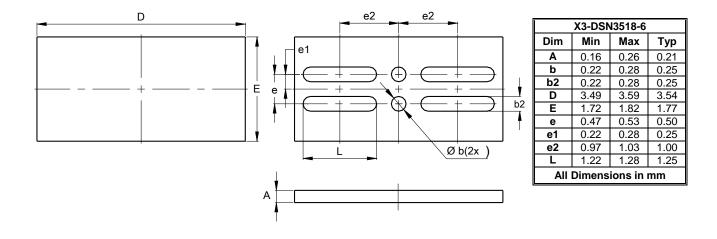




### **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

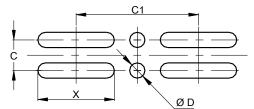
#### X3-DSN3518-6



# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### X3-DSN3518-6



Dimensions	Value (in mm)
С	0.50
C1	2.00
D	0.25
Х	1.25



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